

(43) International Publication Date 1 February 2001 (01.02.2001)

PCT

(10) International Publication Number WO 01/08163 A1

(51) International Patent Classification7: C23C 14/02, 28/00

G21K 5/00,

Drive, Horseheads, NY 14845 (US).

(21) International Application Number: PCT/US00/18798

(22) International Filing Date:

10 July 2000 (10.07.2000)

(25) Filing Language:

English

(26) Publication Language:

English

(30) Priority Data:

22 July 1999 (22.07.1999) US 60/145,057 19 August 1999 (19.08.1999) US 60/149,840 12 October 1999 (12.10.1999) 60/158,813 US

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(81) Designated States (national): AE, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BY, CA, CH, CN, CU, CZ, DE, DK, EE, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MD,

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MG, MK, MN, MW, MX, NO, NZ, PL, PT, RO, RU, SD. SE, SG, SI, SK, SL, TJ, TM, TR, TT, UA, UG, US, UZ, VN, YU, ZA, ZW.

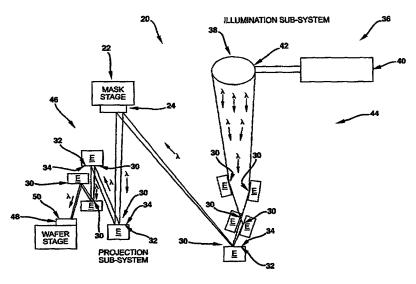
(84) Designated States (regional): European patent (AT, BE, CH, CY, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE).

Published:

With international search report.

For two-letter codes and other abbreviations, refer to the "Guidance Notes on Codes and Abbreviations" appearing at the beginning of each regular issue of the PCT Gazette.

(54) Title: EXTREME ULTRAVIOLET SOFT X-RAY PROJECTION LITHOGRAPHIC METHOD SYSTEM AND LITHOG-RAPHY ELEMENTS



(57) Abstract: The projection lithographic method for producing integrated circuits and forming patterns with extremely small feature dimensions includes an illumination sub-system (36) for producing and directing an extreme ultraviolet soft x-ray radiation λ from an extreme ultraviolet soft x-ray source (38); a mask stage (22) illuminated by the extreme ultraviolet soft x-ray radiation λ produced by illumination stage and the mask stage (22) includes a pattern when illuminated by radiation λ . A protection sub-system includes reflective multilayer coated Ti doped high purity SiO2 glass defect free surface (32) and printed media subject wafer which has a radiation sensitive surface.

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